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Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number. Substitute for form 1449A/PTO Complete if Known INFORMATION DISCLOSURE **Application Number** 10/634,174 STATEMENT BY APPLICANT August 5, 2003 (Use as many sheets as necessary) Filing Date Forbes, Leonard **First Named Inventor** 2823 **Group Art Unit** Garcia, Joannie **Examiner Name** TRADEMARK. Attorney Docket No: 1303.102US1 Sheet 1 of 5

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(Use as many sheets as necessary)	Filing Date	August 5, 2003	
	First Named Inventor	Forbes, Leonard	
	Group Art Unit	2823	
	Examiner Name	Garcia, Joannie	
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• EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered, include copy of this form with next communication to applicant. Applicant's unique citation designation number (optional) a Applicant is to place a check mark here if English language Translation is attached

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(Use as many sheets as necessary)	Filing Date -	August 5, 2003	
	First Named Inventor	Forbes, Leonard	
	Group Art Unit	2823	
Sheet 3 of 5	Examiner Name	Garcia, Joannie	
	Attorney Docket No: 1303.102US1		

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	Examiner Name	Garcia, Joannie		
Sheet 4 of 5	Attorney Docket No: 1	303.102US1		

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Joannie A Hancie

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